

HD151015

9 bit Level Shifter/Transceiver With 3 State Outputs

REJ03D0300-0500 Rev.5.00 May 10, 2006

Description

The HD151015 is an IC which consists of 9 bus transceivers (three state output) in a 24 pin package. Signals are transmitter from A to B when the direction control input (DiR) is at a high level, and from B to A when DiR is at a low level. When the enable input (\overline{G}) is high, A and B are isolated. And this product has two terminals (V_{CCA}, V_{CCB}), V_{CCA} is connected with control input and A bus side, V_{CCB} is connected with B bus side. V_{CCA} and V_{CCB} are isolated. Consequently, it is best to change the level in case of two supply voltage coexist on one board and application of power management.

Features

- This product function as level shift transceiver that change V_{CCA} input level to V_{CCB} output level, V_{CCB} input level to V_{CCA} output level by providing different supply voltages to V_{CCA} and V_{CCB}.
- This product is able to the power management : Turn on and off the supply on V_{CCB} side with providing the supply of V_{CCA} .

(Enable input (\overline{G}) : High level)

- Inputs and outputs are CMOS level, and the power dissipation is the same as CMOS standard logic.
- Wide operating supply voltage range:

 $V_{CCA} = V_{CCB} = 2 \text{ to } 6 \text{ V} (V_{CCB} \ge V_{CCA} - 0.5 \text{ V})$

- Wide operating temperature range: Ta = -40 to $85^{\circ}C$
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)	
HD151015TEL	TSSOP-24 pin	PTSP0024JB-A (TTP-24DBV)	Т	EL (1,000 pcs/reel)	



Pin Arrangement

V _{CCA} 1		24 V _{CCB}
DIR 2		23 G
A0 3		22 B0
A1 4		21 B1
A2 5		20 B2
A3 6		19 B3
A4 7		18 B4
A5 8		17 B5
A6 9		16 B6
A7 10		15 B7
A8 11		14 B8
GND 12		13 GND
l		
	(Top view)	

Function Table

Inputs		
G	DIR	Outputs
L	L	B data to A bus
L	Н	A data to B bus
Н	Х	Z

H : High level

L : Low level

Z : High Impedance

X : Immaterial

Absolute Maximum Ratings

Item	Symbol	Rating	Unit	Conditions
Supply Voltage	V _{CCA} , V _{CCB}	–0.5 to +7.0	V	
Input Diode Current	l _{ik}	-20	mA	V ₁ = -0.5
		20	mA	$V_{I} = V_{CC} + 0.5$
Input Voltage	VIN	–0.5 to V _{CC} + 0.5	V	
Output Diode Current	loк	-50	mA	V _O = -0.5
		50	mA	$V_{\rm O} = V_{\rm CC} + 0.5$
Output Voltage	Vout	–0.5 to V _{CC} + 0.5	V	
Output Current	lo	±50	mA	
VCC or Ground Current	I _{CC} or I _{GND}	±50	mA	per output pin
Storage Temperature	Tstg	–65 to + 150	°C	

Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

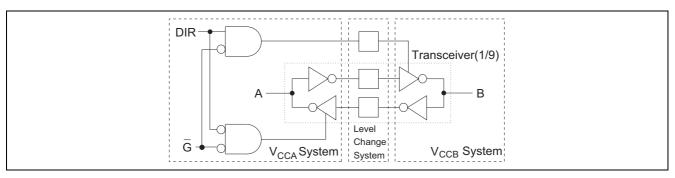


Recommended Operating Conditions

Item	Symbol	Rating	Unit	Conditions
Supply voltage	V _{CCA, B}	2.0 to 6.0	V	$V_{CCB} \ge V_{CCA} - 0.5 V$
Input voltage	V _{IN}	0 to V _{CC}	V	
Output voltage	Vout	0 to V _{CC}	V	
Operating Temperature	T _A	–40 to +85	°C	
Input Rise and Fall Time* ¹	t _r , t _f	8	ns/V	V _{CC} @3.0 V (Input DiR, G, A)
				V _{CC} @4.5 V (Input B)
				V _{CC} @5.5 V (Input B)

Note: 1. The item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.

Logick Diagram



Electrical Characteristics

	Sym-	V _{CCA}	V _{ссв}	1	「a = 25	°C		–40 to °C				
Item	bol	(V)	(V)	Min	Тур	Max	Min	Max	Unit	Conditions		
Input Voltage	VIH	3.0	3.0	2.1	1.5	—	2.1	_	V	V _{OUT} = 0.1 V	or $V_{CC} - 0.1 V$	
		4.5	4.5	3.15	2.25	—	3.15		1			
		5.5	5.5	3.85	2.75	—	3.85		1			
	VIL	3.0	3.0	_	1.5	0.9	_	0.9	V	V _{OUT} = 0.1 V	or V _{CC} – 0.1 V	
		4.5	4.5	_	2.25	1.35	_	1.35	1			
		5.5	5.5	_	2.75	1.65	_	1.65	1			
Output	Voh	2.7	4.5	2.6	2.69	—	2.6		V	$V_{IN} = V_{IL} \text{ or } V_{I}$	н, І _{ОН} = –50 µА	A* ¹
Voltage		2.7	4.5	4.4	4.49	—	4.4		1	$V_{IN} = V_{IL} \text{ or } V_{I}$	_н , I _{он} = –50 µА	В
		2.7	4.5	2.3	—	—	2.2		V	V _{IN} =	I _{OH} =4 mA	A
		2.7	4.5	3.9	—	—	3.8		1	V_{IL} or V_{IH}	I _{ОН} = –12 mA	В
	V _{OL}	2.7	4.5	_	0.001	0.1	_	0.1	V	$V_{IN} = V_{IL} \text{ or } V_{I}$	_H , I _{OL} = 50 μA	A.B
		2.7	4.5	_	—	0.32	_	0.37	V	$V_{IN} = V_{IL} \text{ or } V_{I}$	_H , I _{OL} = 12 mA	A.B
Input Current	I _{IN}	3.3	5.5	_	—	±0.1	_	±1.0	μA	V _{IN} = V _{CC} or GND		
Off State	l _{oz}	3.3	5.5	_	_	±0.5	_	±5.0	μA	$V_{IN}(\overline{G}) = V_{IH}, V_{IN} = V_{CC} \text{ or } GND,$,
Output										$V_{OUT} = V_{CC}$ or GND		
Current												
Supply	I _{CCA.B}	3.3	5.5	—	—	8.0		80	μA	$V_{IN} = V_{CC}$ or GND		
Current	I _{CCA}	5.5	0	_	_	8.0	_	80	μA	$V_{IN} = V_{CC}$ or GND, B Input OPEN		

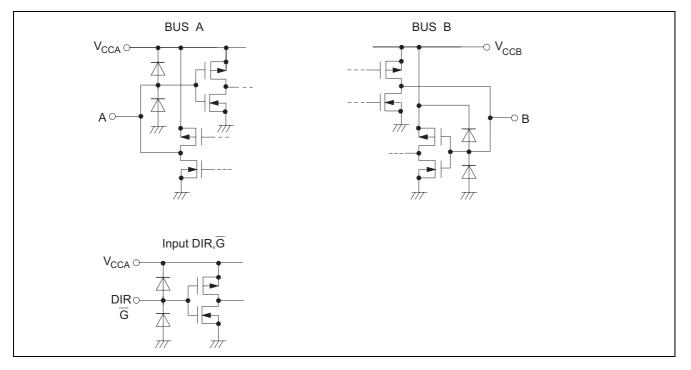
Note: 1. A: Output A, B: Output B, A.B: Output A.B



Switching Characteristics

		Ta = 25°C		Ta = -40 to 85°C				
		$V_{CCA} = 3.0 \text{ V}, V_{CCB} = 5.0 \text{ V}$		$V_{CC} = 2.7 V, V_{CCB} = 4.5 V$				
Item	Symbol	Min Typ Max		Min	Max	Unit	Conditions	
Propagation Delay Time	t _{PLH}	1.0	5.0	10.0	1.0	12.0	ns	$B\toA$
		1.0	5.0	10.0	1.0	12.0		$A \rightarrow B$
	t _{PHL}	1.0	5.0	10.0	1.0	12.0	ns	$B\toA$
		1.0	5.0	10.0	1.0	12.0		$A \rightarrow B$
Output Enable Time	t _{zH}	1.0	8.0	16.0	1.0	20.0	ns	$\overline{G} \to A$
		1.0	8.0	16.0	1.0	20.0		$\overline{G} \to B$
	t _{ZL}	1.0	9.0	16.0	1.0	20.0	ns	$\overline{G} \to A$
		1.0	9.0	16.0	1.0	20.0		$\overline{G} \to A$
Output Disable Time	t _{HZ}	1.0	9.0	16.0	1.0	20.0	ns	$\overline{G} \to A$
		1.0	9.0	16.0	1.0	20.0		$\overline{G} \to B$
	t _{LZ}	1.0	8.0	16.0	1.0	20.0	ns	$\overline{G} \to A$
		1.0	8.0	16.0	1.0	20.0		$\overline{G} \to B$

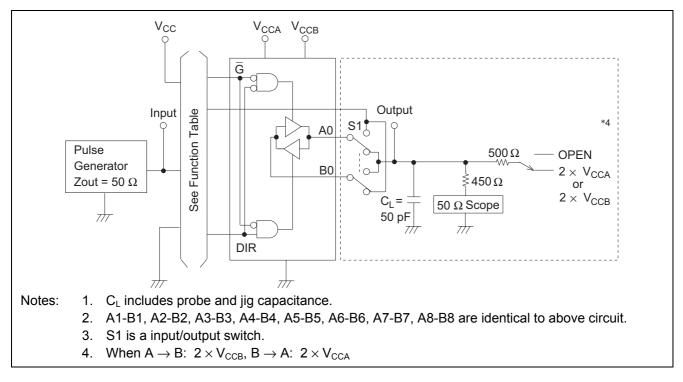
Input and Output Equivalent Circuit





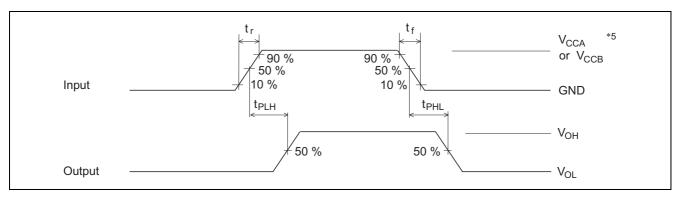
Switching Time Test Method

Test Circuit

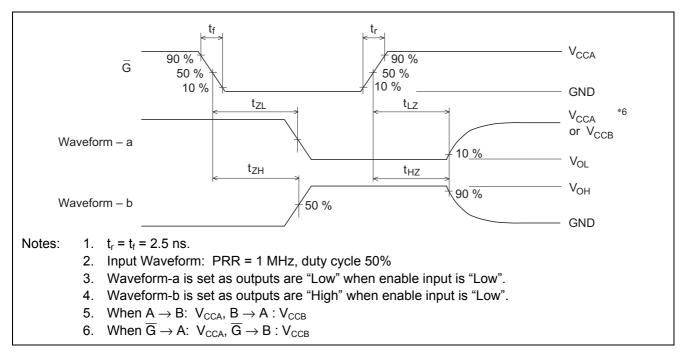




Waveforms-1



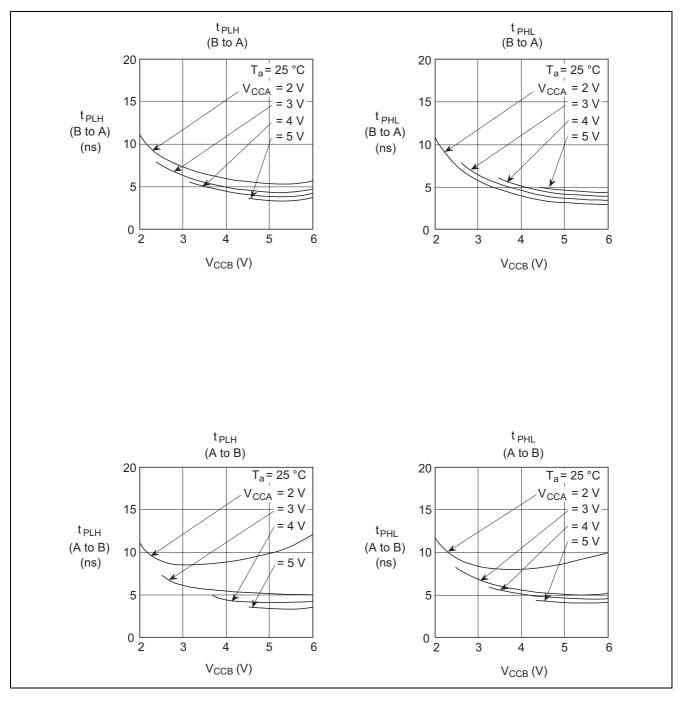
Waveforms-2





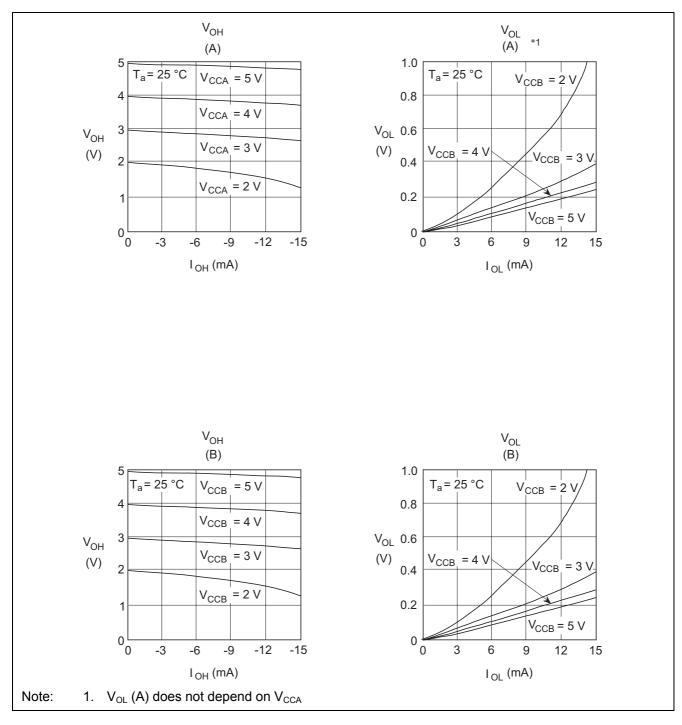
Typical Characteristic Curves

Propagation Delay Times vs Power Supply (V_{CCA} , V_{CCB})





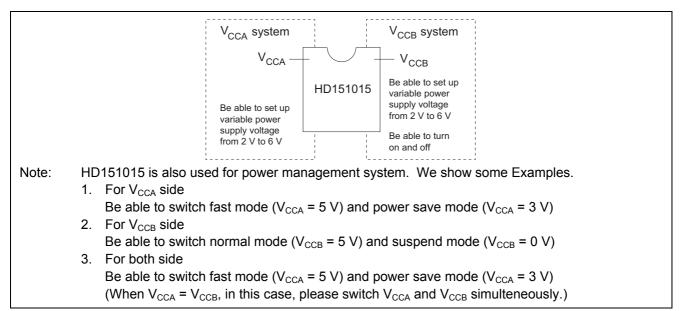
Output Voltage vs Output Current



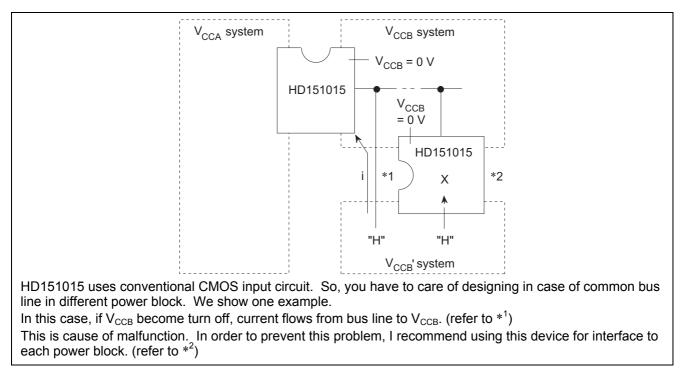


Application

For power management system (1)



For power management system (2) (Common bus line in different power system)

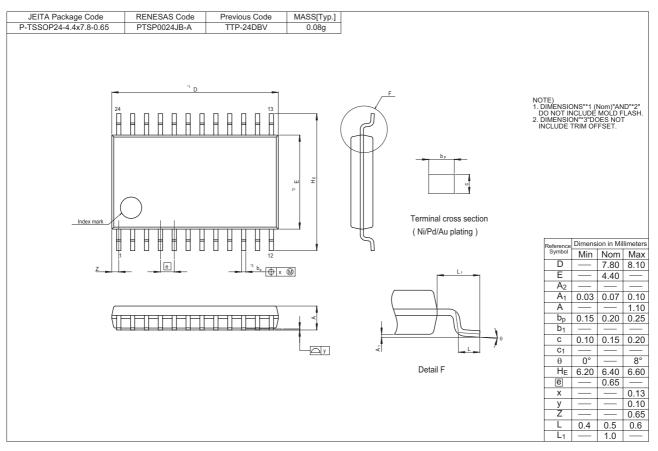


[Cautions on using]

Please use this IC on condition of V_{CCA} usually ON, because if you use it on condition of V_{CCA} being OFF, V_{CCB} being ON, it will be troubled.



Package Dimensions





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Renesas Technology Malaysia Sdn. Bhd Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

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